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Kind regards,

Team Nexperia



PESD5V0X2UAMB

Ultra low capacitance unidirectional double ESD protection diode

10 April 2014

Product data sheet

1. General description

Ultra low capacitance unidirectional double ElectroStatic Discharge (ESD) protection diode in a DFN1006B-3 (SOT883B) leadless ultra small Surface-Mounted Device (SMD) plastic package designed to protect up to two signal lines from the damage caused by ESD and other transients.

2. Features and benefits

- Ultra low diode capacitance: C_d = 0.8 pF
- Ultra low package height of only 0.37 mm
- ESD protection up to 15 kV; IEC61000-4-2
- I_{PPM} = 2.5 A; IEC 61643-321 (surge)
- AEC-Q101 qualified

3. Applications

- High-speed data lines
- Portable electronics
- Communication systems
- Computers and peripherals

4. Quick reference data

Table 1. Quick reference data

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
Per diode							
C _d	diode capacitance	f = 1 MHz; V _R = 0 V	[1]	-	0.8	0.95	pF
V _{RWM}	reverse standoff voltage			-	-	5	V

[1] Measured from pin 1 or 2 to 3.





5. Pinning information

Table 2. Pinning information

Pin	Symbol	Description	Simplified outline	Graphic symbol
1	K1	cathode (diode 1)	1 🔲	1
2	K2	cathode (diode 2)	3	2 3
3	A	common anode	Transparent top view	brb051
			DFN1006B-3 (SOT883B)	

6. Ordering information

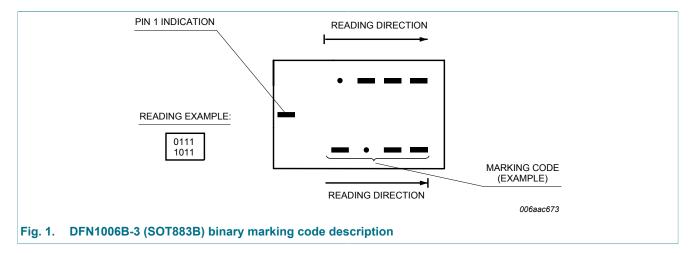
Table 3. Ordering information

Type number	Package					
	Name	Description	Version			
PESD5V0X2UAMB	DFN1006B-3	DFN1006B-3: leadless ultra small plastic package; 3 solder lands; body 1.0 x 0.6 x 0.37 mm	SOT883B			

7. Marking

Table 4. Marking codes

Type number	Marking code
PESD5V0X2UAMB	0100 1111



8. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions		Min	Max	Unit
Per diode						,
I _{PPM}	rated peak pulse current	t _p = 8/20 μs	[1][2]	-	2.5	Α
Tj	junction temperature			-	150	°C
T _{stg}	storage temperature			-55	150	°C
T _{amb}	ambient temperature			-65	150	°C
ESD maximu	um ratings					
V _{ESD}	electrostatic discharge voltage	IEC 61000-4-2 (contact discharge)	[3][2]	-	15	kV
		IEC 61000-4-2 (air discharge)	[3][2]	-	15	kV
		machine model	[2]	-	400	V
		MIL-STD-883 (human body model)		-	10	kV

- [1] According to IEC 61000-4-5 and IEC 61643-321.
- [2] Measured from pin 1 or 2 to 3.
- [3] Device stressed with ten non-repetitive ESD pulses.

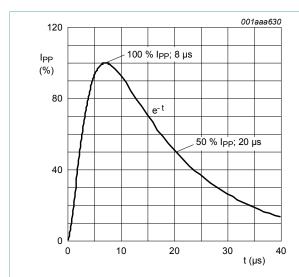


Fig. 2. 8/20 μs pulse waveform according to IEC 61000-4-5 and IEC 61643-321

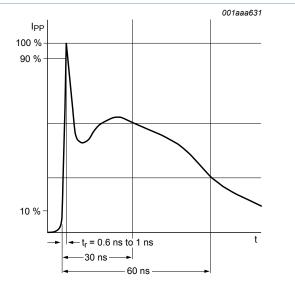


Fig. 3. ESD pulse waveform according to IEC 61000-4-2

9. Characteristics

Table 6. Characteristics

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
Per diode			'				
V_{RWM}	reverse standoff voltage			-	-	5	V
I _{RM}	reverse leakage current	V _R = 5 V	[1]	-	1	10	nA
V_{CL}	clamping voltage	I_{PP} = 1 A; t_p = 8/20 μ s	[2][1]	-	-	13	V
		I_{PP} = 2.5 A; t_p = 8/20 µs	[2][1]	-	-	14	V
V_{BR}	breakdown voltage	I _R = 10 mA	[1]	7.5	8.8	10	V
C _d	diode capacitance	f = 1 MHz; V _R = 0 V	[1]	-	0.8	0.95	pF
R _{dyn}	dynamic resistance	I _R = 10 A	[3][1]	-	0.65	-	Ω

- [1] Measured from pin 1 or 2 to 3.
- [2] According to IEC 61000-4-5 and IEC 61643-321.
- [3] Non-repetitive current pulse, Transmission Line Pulse (TLP); square pulse; ANSI / ESD STM5.5.1-2008.

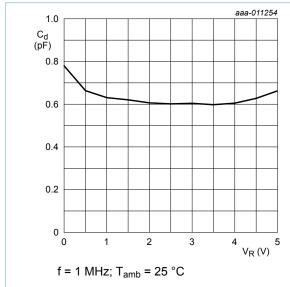


Fig. 4. Diode capacitance as a function of reverse voltage; typical values

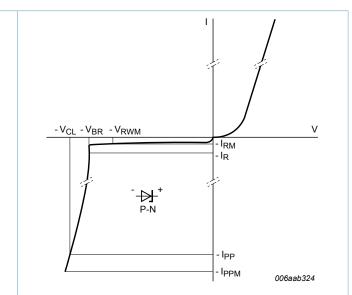
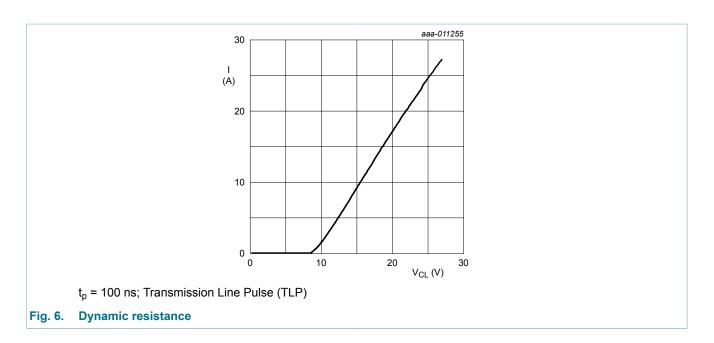
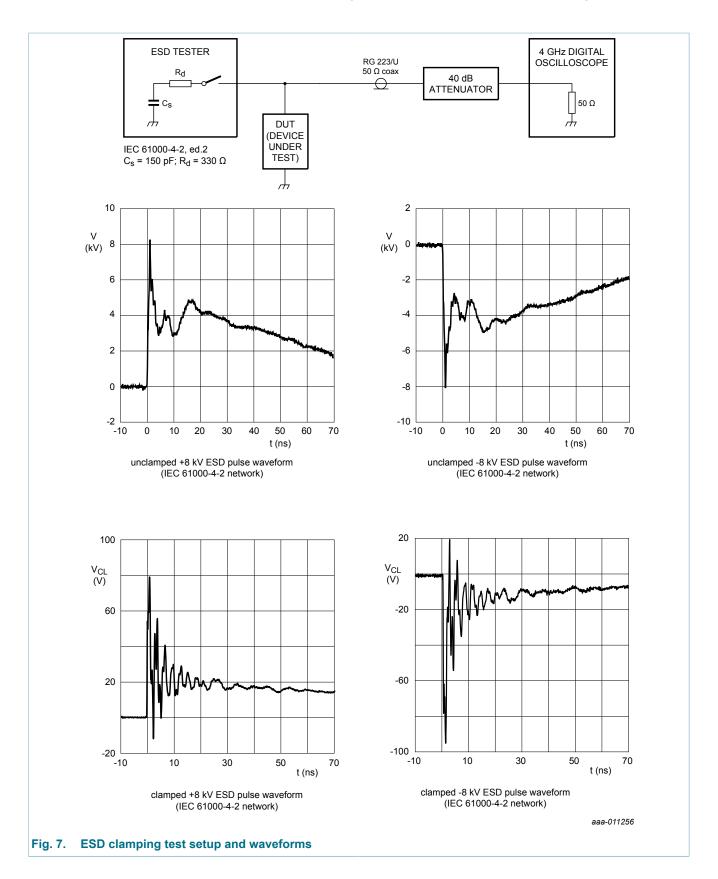


Fig. 5. V-I characteristics for a unidirectional ESD protection diode





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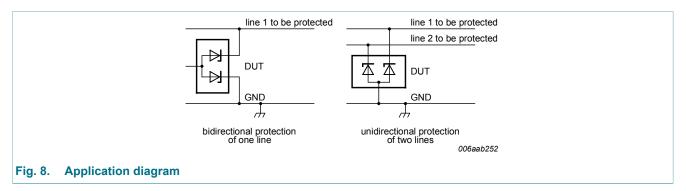
10. Test information

10.1 Quality information

This product has been qualified in accordance with the Automotive Electronics Council (AEC) standard Q101 - Stress test qualification for discrete semiconductors, and is suitable for use in automotive applications.

11. Application information

The device is designed for the protection of up to two unidirectional data lines from surge pulses and ESD damage.

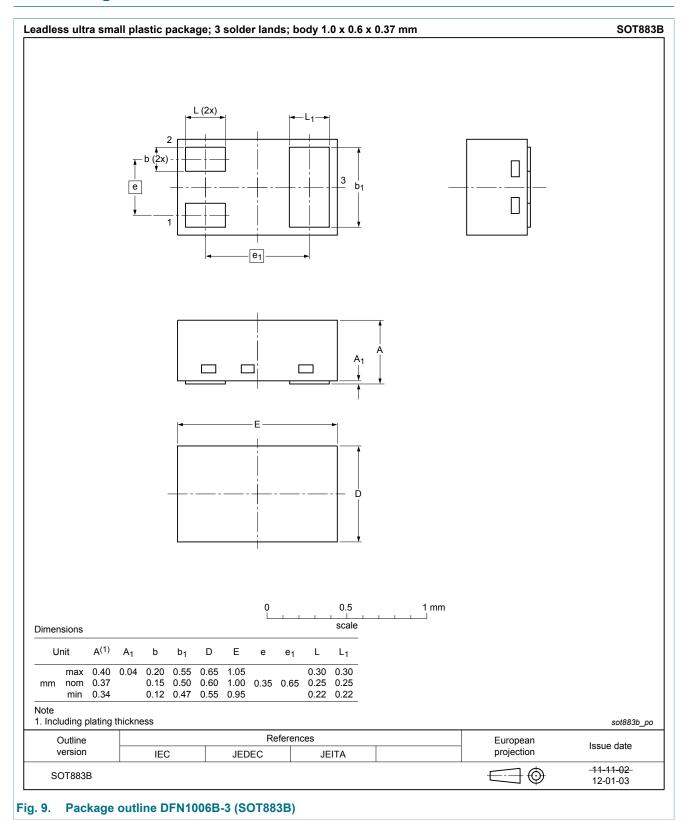


Circuit board layout and protection device placement

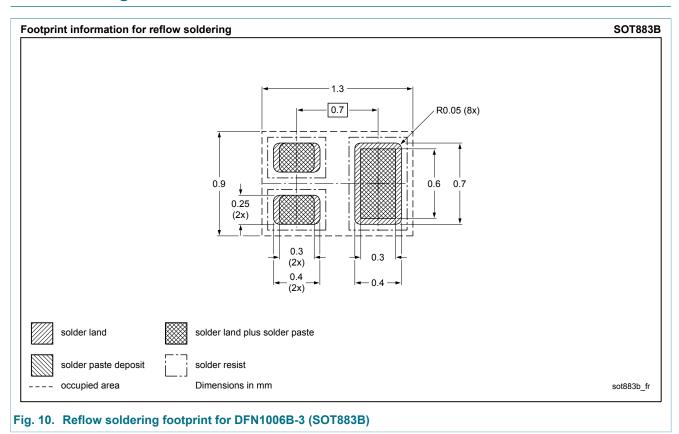
Circuit board layout is critical for the suppression of ESD, Electrical Fast Transient (EFT) and surge transients. The following guidelines are recommended:

- 1. Place the device as close to the input terminal or connector as possible.
- 2. Minimize the path length between the device and the protected line.
- 3. Keep parallel signal paths to a minimum.
- 4. Avoid running protected conductors in parallel with unprotected conductors.
- 5. Minimize all Printed-Circuit Board (PCB) conductive loops including power and ground loops.
- 6. Minimize the length of the transient return path to ground.
- 7. Avoid using shared transient return paths to a common ground point.
- 8. Use ground planes whenever possible. For multilayer PCBs, use ground vias.

12. Package outline



13. Soldering



14. Revision history

Table 7. Revision history

Data sheet ID	Release date	Data sheet status	Change notice	Supersedes
PESD5V0X2UAMB v.1	20140410	Product data sheet	-	-

15. Legal information

15.1 Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

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12/13

16. Contents

1	General description	1
2	Features and benefits	1
3	Applications	1
4	Quick reference data	1
5	Pinning information	2
6	Ordering information	2
7	Marking	2
8	Limiting values	3
9	Characteristics	4
10	Test information	7
10.1	Quality information	7
11	Application information	7
12	Package outline	8
13	Soldering	9
14	Revision history	10
15	Legal information	11
15.1	Data sheet status	11
15.2	Definitions	11
15.3	Disclaimers	11
15.4	Trademarks	12

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